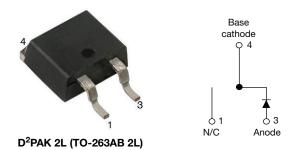
**Vishay Semiconductors** 

# Ultrafast Rectifier, 30 A FRED Pt®



www.vishay.com

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	30 A								
V <sub>R</sub>	600 V								
V <sub>F</sub> at I <sub>F</sub>	0.9 V								
t <sub>rr</sub> (typ.)	110 ns								
T <sub>J</sub> max.	175 °C								
Package	D <sup>2</sup> PAK 2L (TO-263AB 2L)								
Circuit configuration	Single								

### **FEATURES**

- Low forward voltage drop
- Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

Ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for discontinuous (critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 125 °C	30	٨						
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	280	A						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-					
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.01	1.1	V				
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	0.90	1.02					
		$V_{\rm R} = V_{\rm R}$ rated	-	0.02	30					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	250	μΑ				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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RoHS COMPLIANT

HALOGEN

FREE



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100$	0 A/µs, V <sub>R</sub> = 30 V	-	110	-				
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	134	-	ns A			
		T <sub>J</sub> = 125 °C		-	176	-				
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_{\rm F} = 30  {\rm A}$	-	76	-				
Feak recovery current		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 1000 A/µs V <sub>B</sub> = 400 V	-	94	-	A			
Reverse recovery charge	0	T <sub>J</sub> = 25 °C	]	-	6670	-				
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	10 300	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C			
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	0.95	1.2	°C/W			
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70				
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2.0	-	g			
weight			-	0.07	-	oz.			
Marking device		Case style D <sup>2</sup> PAK 2L (TO-263AB 2L)		ETL3	006SH				

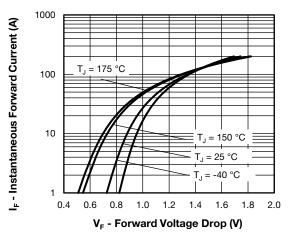


Fig. 1 - Typical Forward Voltage Drop Characteristics

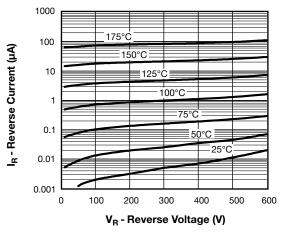


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

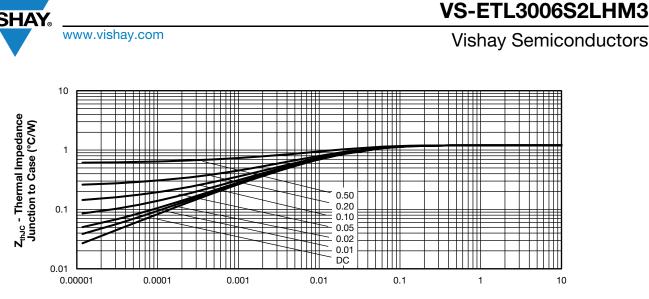




Fig. 3 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

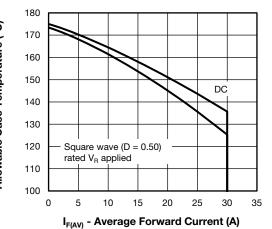


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current



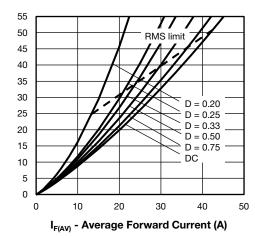
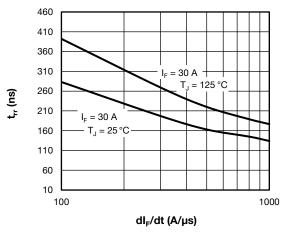


Fig. 5 - Forward Power Loss Characteristics





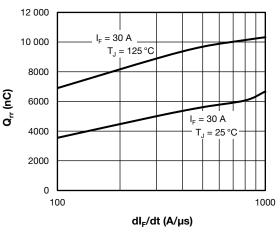


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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Allowable Case Temperature (°C)

## VS-ETL3006S2LHM3

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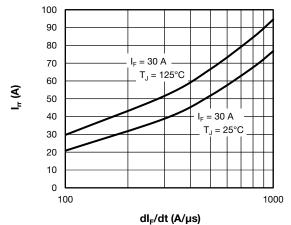


Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

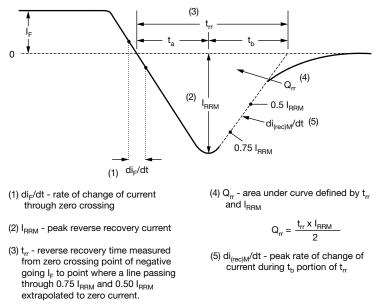


Fig. 9 - Reverse Recovery Waveform and Definitions

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**ORDERING INFORMATION TABLE** 

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VISHA

Device code	VS-	Е	т	L	30	06	S2	L	н	М3
		2	3	4	5	6	7	8	9	10
	1 - Vishay Semiconductors product									
	2									
	3									
	4	- L=	ultrafas	t recove	ery time					
	5	- Cur	rent coo	de (30 =	30 A)					
	6	- Volt	tage coo	de (06 =	600 V)					
	7	- S2	= true 2	pin D <sup>2</sup> F	PAK					
	8	8 - • None = tube								
	<ul> <li>• L = tape and reel (left oriented, for D<sup>2</sup>PAK package)</li> <li>If needed different orientation/packaging, please contact factory</li> </ul>									
	9	9 - H = AEC-Q101 qualified								
	10 ·	- Env	vironmer	ntal digit	:					
				-						

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-ETL3006S2LHM3	800	13" diameter reel						

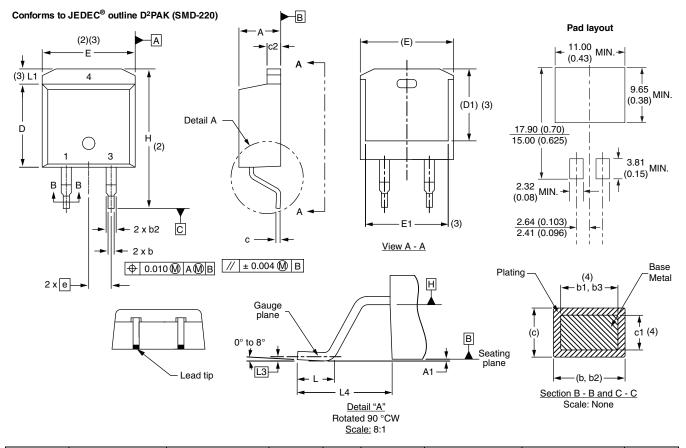
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96683					
Part marking information	www.vishay.com/doc?96693					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?97299					

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D<sup>2</sup>PAK 2L (TO-263AB 2L)

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SY		MILLIM	IETERS	INC	HES	NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3		
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3		
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3		
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625			
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110			
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3		
c1	0.38	0.58	0.015	0.023	4		L3	0.25 BSC		L3 0.25 BSC		0.010	BSC	
c2	1.14	1.65	0.045	0.065			L4	4.78	5.28	0.188	0.208			
D	8.51	9.65	0.335	0.380	2									

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
 (3) Thermal and contain antional within dimension E 1.1, D1 and E1.

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

(7) Outline conforms to JEDEC® outline TO-263AB

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